

| L Number | Hits | Search Text   | DB  | Time stamp       |
|----------|------|---|---|------------------|
| 1        | 5158 | 438/184,230-232,265,301,303-306,595.ccls.   | USPAT;<br>US-PGPUB;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | 2004/11/06 09:22 |
| 2        | 699  | 438/184,230-232,265,301,303-306,595.ccls. and source and drain and (junction adj depth\$4)  | USPAT;<br>US-PGPUB;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | 2004/11/06 09:23 |
| 3        | 530  | (438/184,230-232,265,301,303-306,595.ccls. and source and drain and (junction adj depth\$4)) and (ion adj implantation)   | USPAT;<br>US-PGPUB;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | 2004/11/06 09:24 |
| 4        | 436  | ((438/184,230-232,265,301,303-306,595.ccls. and source and drain and (junction adj depth\$4)) and (ion adj implantation)) and (liner or spacer\$2 or sidewall\$4)   | USPAT;<br>US-PGPUB;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | 2004/11/06 09:24 |
| 5        | 334  | ((((438/184,230-232,265,301,303-306,595.ccls. and source and drain and (junction adj depth\$4)) and (ion adj implantation)) and (liner or spacer\$2 or sidewall\$4)) and (oxide or dioxide) and (nitride or oxynitride)             | USPAT;<br>US-PGPUB;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | 2004/11/06 09:25 |
| 6        | 246  | (((((438/184,230-232,265,301,303-306,595.ccls. and source and drain and (junction adj depth\$4)) and (ion adj implantation)) and (liner or spacer\$2 or sidewall\$4)) and (oxide or dioxide) and (nitride or oxynitride)) and boron | USPAT;<br>US-PGPUB;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | 2004/11/06 09:25 |